## FEATURES

- **Integrated Mixer/Oscillator/PLL and IF GCA**
- **VHF-L, VHF-H, UHF Three-Band Local Oscillator**
- **RF AGC Detector Circuit**
- **I²C Bus Protocol Bidirectional Data Transmission**
- **High-Voltage Tuning Voltage Output**
- **Four NPN-Type Band-Switch Drivers**
- **One Auxiliary Port/5-Level ADC**
- **Crystal Oscillator Output**
- **Programmable Reference Divider Ratio (24/28/50/64/80/128)**
- **Low Distortion IF Gain Controlled Amplifier**
- **Standby Mode**
- **5-V Power Supply**
- **40-Pin Quad Flatpack No-Lead (QFN) Package**

APPLICATIONS

- **Digital TV**
- **Digital CATV**
- **Set-Top Box**

QFN PACKAGE
(TOP VIEW)

Top pins (40–31): OSC GND, VHI OSC C, VHI OSC B, VLO OSC C, VLO OSC B, BS4, UHF RF IN1, UHF RF IN2, VHI RF IN, VLO RF IN

Left pin	#		#	Right pin
UHF OSC B1	1		30	RF GND
UHF OSC C1	2		29	MIXOUT1
UHF OSC C2	3		28	MIXOUT2
UHF OSC B2	4		27	RF AGC OUT
IF GND	5		26	RF AGC FIL
IF OUT1	6		25	BS3
IF OUT2	7		24	BS2
CP	8		23	BS1
VTU	9		22	SDA
V_CC	10		21	SCL

Bottom pins (11–20): IF GCA IN1, IF GCA IN2, IF GCA CTRL, IF GCA OUT2, IF GCA OUT1, P5/ADC, XTAL1, XTAL2, XTAL OUT, AS

DESCRIPTION

The SN761667 is a low-phase-noise synthesized tuner IC designed for digital TV tuning systems. The circuit consists of a PLL synthesizer, three-band local oscillator and mixer, RF AGC detector circuit, and IF gain-controlled amplifier. The SN761667 is available in a small QFN package.
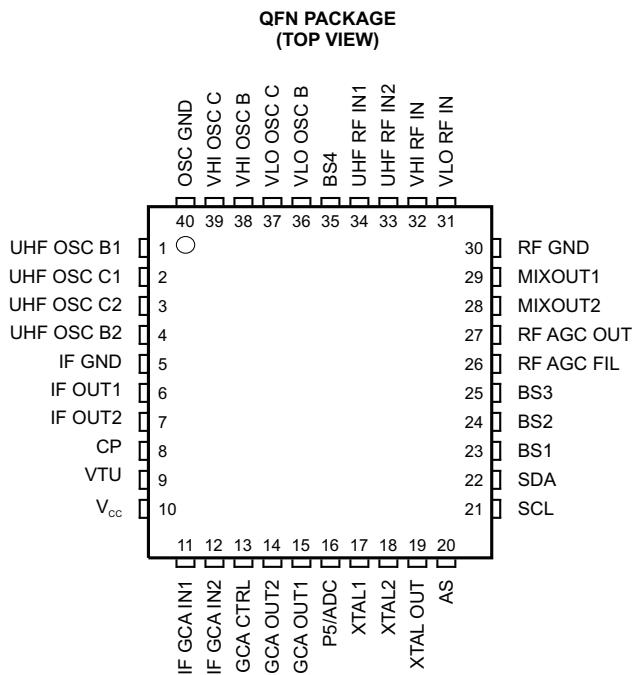
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FUNCTIONAL BLOCK DIAGRAM

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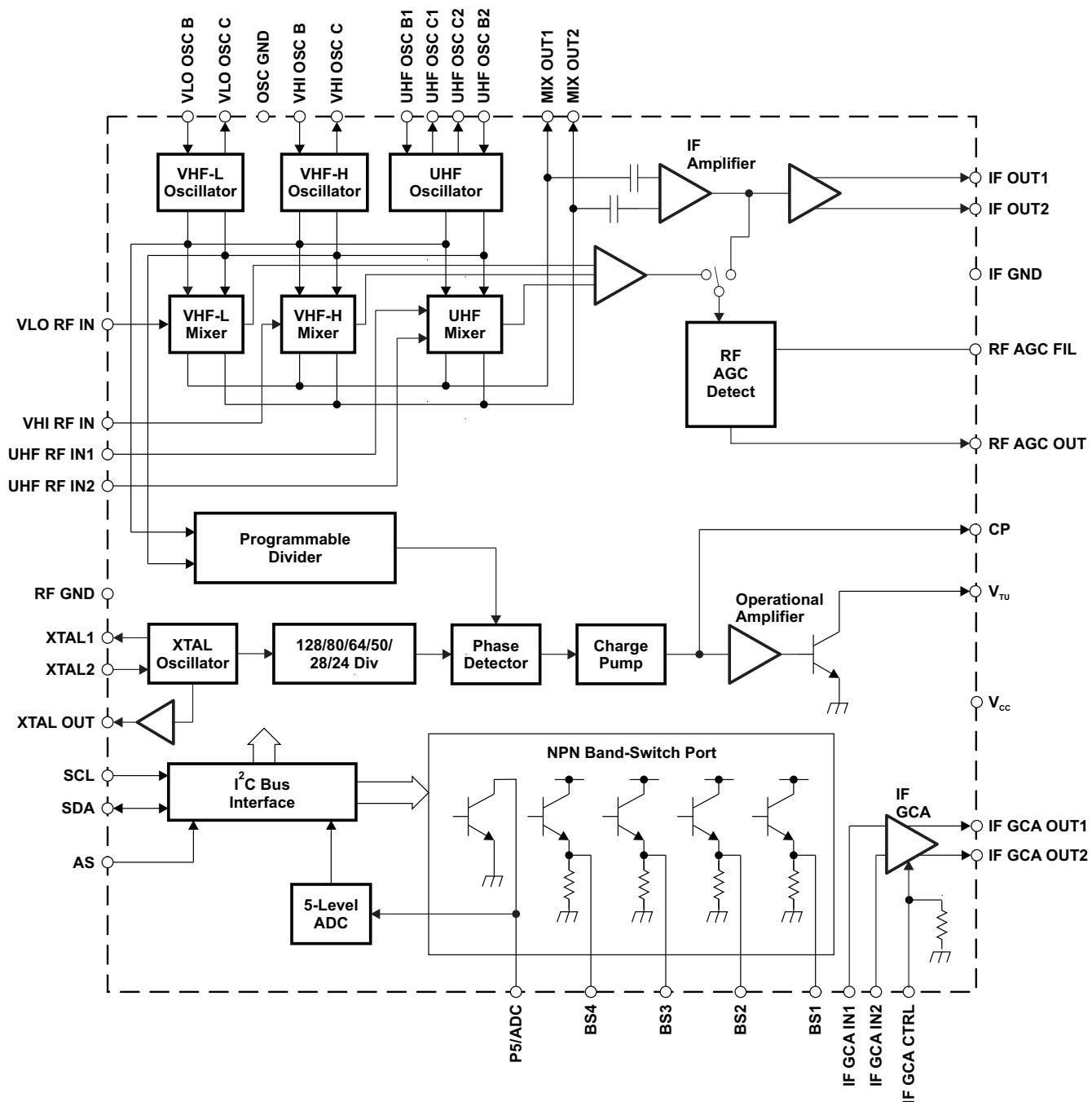
TERMINAL FUNCTIONS

TERMINAL		DESCRIPTION	SCHEMATIC
NAME	NO.		
AS	20	Address selection input	Figure 1
BS1	23	Band-switch 1 output	Figure 2
BS2	24	Band-switch 2 output	Figure 2
BS3	25	Band-switch 3 output	Figure 2
BS4	35	Band-switch 4 output	Figure 2
CP	8	Charge-pump output	Figure 3
IF GCA CTRL	13	IF GCA CTRL voltage input	Figure 4
IF GCA IN1	11	IF GCA input 1	Figure 5
IF GCA IN2	12	IF GCA input 2	Figure 5
IF GCA OUT1	15	IF GCA output 1	Figure 6
IF GCA OUT2	14	IF GCA output 2	Figure 6
IF GND	5	IF ground	
IF OUT1	6	IF amplifier output 1	Figure 7
IF OUT2	7	IF amplifier output 2	Figure 7
MIX OUT1	29	Mixer output 1	Figure 8
MIX OUT2	28	Mixer output 2	Figure 8
OSC GND	40	Oscillator ground	
P5/ADC	16	Port-5 output/ADC input	Figure 9
RF AGC FIL	26	RF AGC additional capacitor pin	Figure 10
RF AGC OUT	27	RF AGC output	Figure 11
RF GND	30	RF ground	
SCL	21	Serial clock input	Figure 12
SDA	22	Serial data input/output	Figure 13
UHF OSC B1	1	UHF oscillator base 1	Figure 14
UHF OSC B2	4	UHF oscillator base 2	Figure 14
UHF OSC C1	2	UHF oscillator collector 1	Figure 14
UHF OSC C2	3	UHF oscillator collector 2	Figure 14
UHF RF IN1	34	UHF RF input 1	Figure 15
UHF RF IN2	33	UHF RF input 2	Figure 15
V_{CC}	10	Supply voltage: 5 V	
VHI OSC B	38	VHF HIGH oscillator base	Figure 16
VHI OSC C	39	VHF HIGH oscillator collector	Figure 16
VHI RF IN	32	VHF-H RF input	Figure 17
VLO OSC B	36	VHF LOW oscillator base	Figure 18
VLO OSC C	37	VHF LOW oscillator collector	Figure 18
VLO RF IN	31	VHF-L RF input	Figure 19
VTU	9	Tuning voltage amplifier output	Figure 3
XTAL1	17	4-MHz crystal oscillator output	Figure 20
XTAL2	18	4-MHz crystal oscillator input	Figure 20
XTAL OUT	19	4-MHz crystal oscillator output	Figure 21

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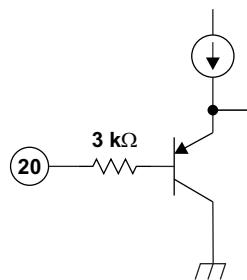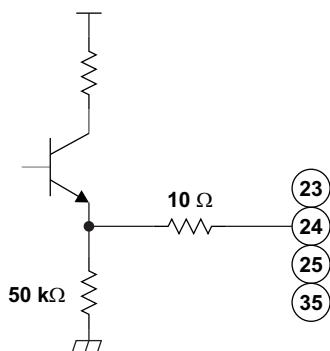
Figure 1. AS



Figure 2. BS1, BS2, BS3, and BS4
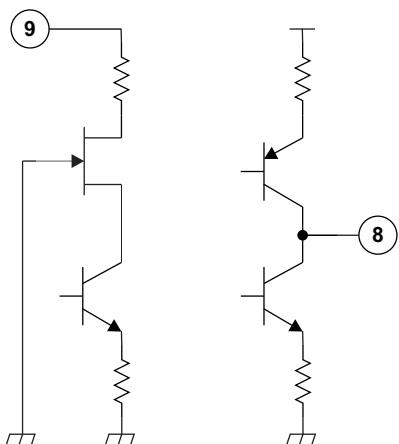

Figure 3. CP and VTU
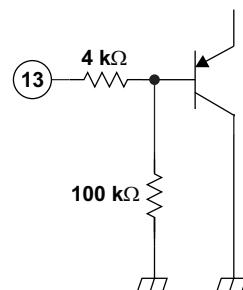


Figure 4. IF GCA CTRL
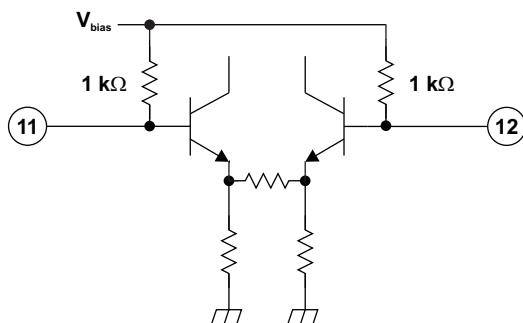

Figure 5. IF GCA IN1 and IF GCA IN2
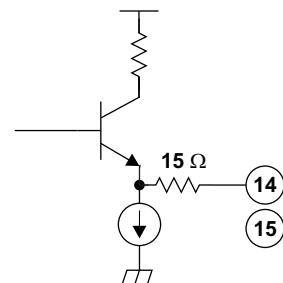
Figure 6. IF GCA OUT1 and IF GCA OUT2
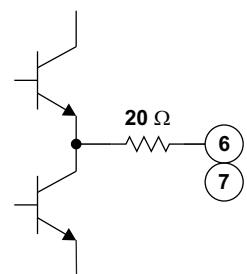
Figure 7. IF OUT1 and IF OUT2
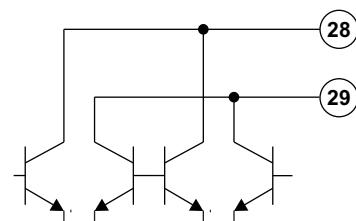
Figure 8. MIX OUT1 and MIX OUT2
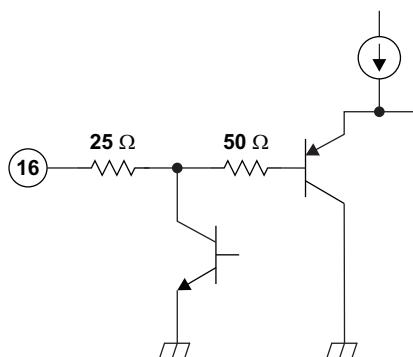
Figure 9. P5/ADC
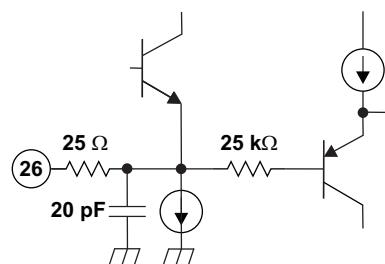
Figure 10. RF AGC FIL
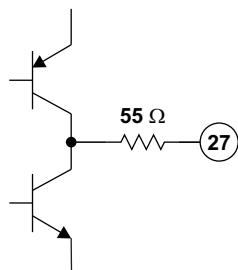
Figure 11. RF AGC OUT
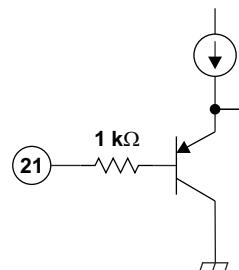
Figure 12. SCL
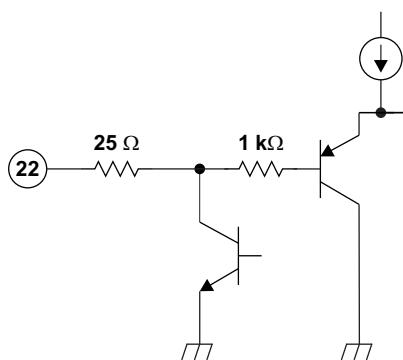
Figure 13. SDA
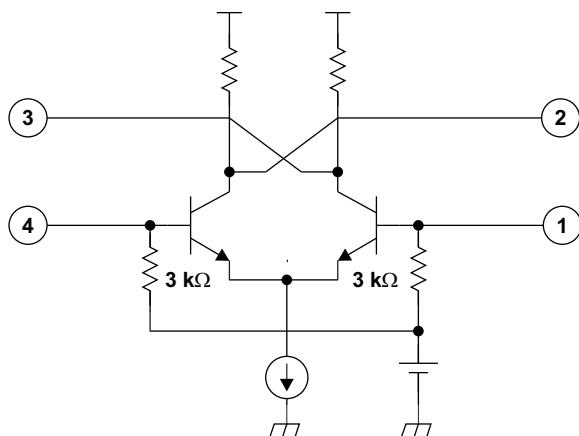
Figure 14. UHF OSC B1, UHF OSC B2, UHF OSC C1, and UHF OSC C2
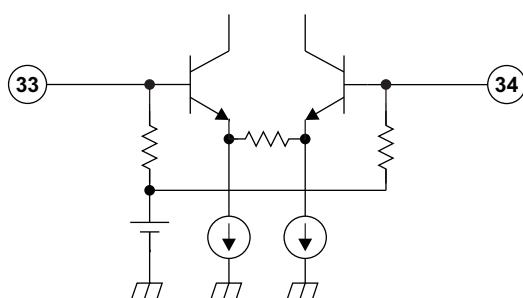
Figure 15. UHF RF IN1 and UHF RFIN2
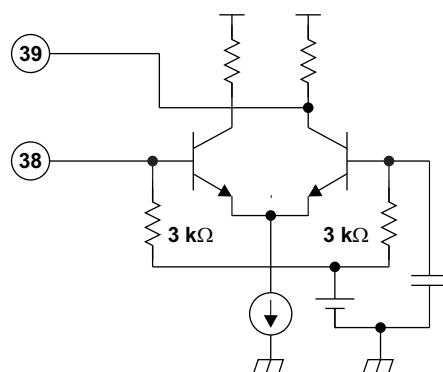
Figure 16. VHI OSC B and VHI OSC C

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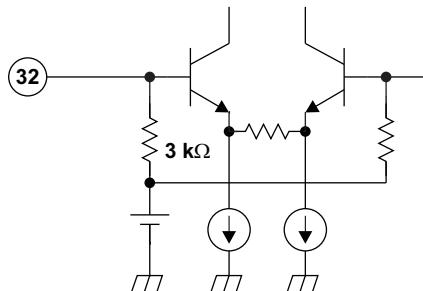
Figure 17. VHI RF IN
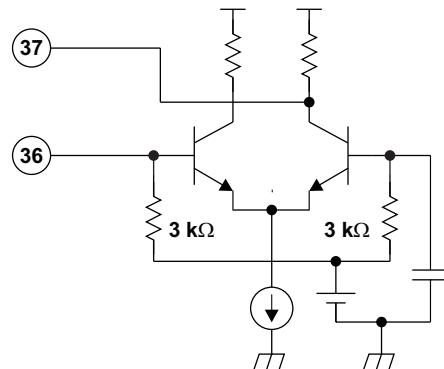
Figure 18. VLO OSC B and VLO OSC C
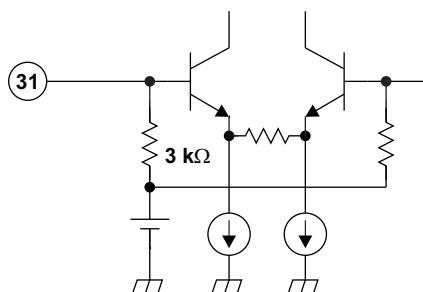
Figure 19. VLO RF IN
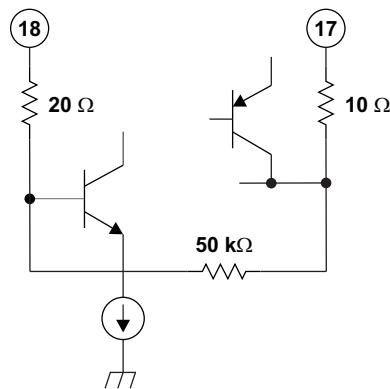
Figure 20. XTAL1 and XTAL2
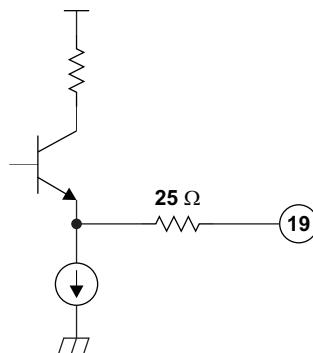
Figure 21. XTAL OUT

Absolute Maximum Ratings[1]

over recommended operating free-air temperature range (unless otherwise noted)

|			MIN	MAX	UNIT
V_{CC}	Supply voltage range [2]	V_{CC}	−0.4	6.5	V
V_{GND}	Input voltage 1 [2]	RF GND, OSC GND	−0.4	0.4	V
VTU	Input voltage 2 [2]	VTU	−0.4	35	V
V_{IN}	Input voltage 3 [2]	Other pins	−0.4	6.5	V
θ_{JA}	Package thermal impedance [3]			32.5	°C/W
T_A	Operating free-air temperature range		−20	85	°C
T_{stg}	Storage temperature range		−65	150	°C
T_{JC}	Maximum junction temperature			150	°C
$t_{SC(max)}$	Maximum short-circuit time	Each pin to V_{CC} or to GND		10	s

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) Voltage values are with respect to the IF GND of the circuit.
(3) The package thermal impedance is calculated in accordance with JESD 51-5.

Recommended Operating Conditions

			MIN	NOM	MAX	UNIT
V_{CC}	Supply voltage		4.5	5	5.5	V
VTU	Tuning supply voltage			30	33	V
I_{BS}	Output current of band-switch	BS1–BS4, one band switch on			10	mA
I_{P5}	Output current of port 5	P5/ADC			−5	mA
T_A	Operating free-air temperature		−20		85	°C

![ESD warning symbols] This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

MIXOUT1 and MIXOUT2 (pins 28 and 29) withstand 1.5 kV and all other pins withstand 2 kV, according to the Human-Body Model (1.5 kΩ, 100 pF).

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Electrical Characteristics – Total Device and Serial Interface

V_{CC} = 4.5 V to 5.5 V, T_A = −20°C to 85°C (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$I_{CC}1$	Supply current 1			115	140	mA
$I_{CC}2$	Supply current 2	One band switch on (I_{BS} = 10 mA)		125	150	mA
$I_{CC-STBY}$	Standby supply current	STBY = 1		9		mA
V_{IH}	High-level input voltage (SCL, SDA)		2.5			V
V_{IL}	Low-level input voltage (SCL, SDA)				1.35	V
I_{IH}	High-level input current (SCL, SDA)				10	µA
I_{IL}	Low-level input current (SCL, SDA)		−10			µA
V_{POR}	Power-on-reset supply voltage (threshold of supply voltage between reset and operation mode)		2.1	2.8	3.5	V
I²C Interface						
V_{ASH}	Address-select high-input voltage (AS)	V_{CC} = 5 V	4.5		5	V
V_{ASM1}	Address-select mid-input 1 voltage (AS)	V_{CC} = 5 V	2		3	V
V_{ASM2}	Address-select mid-input 2 voltage (AS)	V_{CC} = 5 V	1		1.5	V
V_{ASL}	Address-select low-input voltage (AS)	V_{CC} = 5 V			0.5	V
I_{ASH}	Address-select high-input current (AS)				10	µA
I_{ASL}	Address-select low-input current (AS)		−10			µA
V_{ADC}	ADC input voltage	See Table 10	0		V_{CC}	V
I_{ADH}	ADC high-level input current	V_{ADC} = V_{CC}			10	µA
I_{ADL}	ADC low-level input current	V_{ADC} = 0 V	−10			µA
V_{OL}	Low-level output voltage (SDA)	V_{CC} = 5 V, I_{OL} = 3 mA			0.4	V
I_{SDAH}	High-level output leakage current (SDA)	V_{SDA} = 5.5 V			10	µA
f_{SCL}	Clock frequency (SCL)			100	400	kHz
t_{HD-DAT}	Data hold time	See Figure 22	0			µs
t_{BUF}	Bus free time		1.3			µs
t_{HD-STA}	Start hold time		0.6			µs
t_{LOW}	SCL-low hold time		0.6			µs
t_{HIGH}	SCL-high hold time		0.6			µs
t_{SU-STA}	Start setup time		0.6			µs
t_{SU-DAT}	Data setup time		0.1			µs
t_r	Rise time (SCL, SDA)				0.3	µs
t_f	Fall time (SCL, SDA)				0.3	µs
t_{SU-STO}	Stop setup time		0.6			µs

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Electrical Characteristics – PLL and Band Switch

V_{CC} = 4.5 V to 5.5 V, T_A = –20°C to 85°C (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
N	Divider ratio	15-bit frequency word	512		32767	
f_{XTAL}	Crystal oscillator frequency	R_{XTAL} = 25 Ω to 300 Ω		4		MHz
Z_{XTAL}	Crystal oscillator input impedance			1.6		kΩ
V_{XLO}	XTAL OUT output voltage	Load = 10 pF/5.1 kΩ, V_{CC} = 5 V, T_A = 25°C		0.4		Vp-p
V_{VTUL}	Tuning amplifier low-level output voltage	R_L = 22 kΩ, VTU = 33 V	0.2	0.3	0.46	V
I_{VTUOFF}	Tuning amplifier leakage current	Tuning amplifier = off, VTU = 33 V			10	μA
I_{CP11}	Charge-pump current	CP[1:0] = 11		600		μA
I_{CP10}		CP[1:0] = 10		350		
I_{CP01}		CP[1:0] = 01		140		
I_{CP00}		CP[1:0] = 00		70		
V_{CP}	Charge-pump output voltage	PLL locked		1.95		V
I_{CPOFF}	Charge-pump leakage current	V_{CP} = 2 V, T_A = 25°C	–15		15	nA
I_{BS}	Band-switch driver output current (BS1–BS4)				10	mA
V_{BS1}	Band-switch driver output voltage (BS1–BS4)	I_{BS} = 10 mA	3			V
V_{BS2}		I_{BS} = 10 mA, V_{CC} = 5 V, T_A = 25°C	3.5	3.9		
I_{BSOFF}	Band-switch driver leakage current (BS1–BS4)	V_{BS} = 0 V			8	μA
I_{P5}	Band-switch port sink current (P5/ADC)				–5	mA
V_{P5ON}	Band-switch port output voltage (P5/ADC)	I_{P5} = –2 mA, V_{CC} = 5 V, T_A = 25°C			0.6	V

Electrical Characteristics – RF AGC

V_{CC} = 5 V, T_A = 25°C, measured in Figure 23 reference measurement circuit at 50-Ω system, IF = 44 MHz, IF filter characteristics: f_{peak} = 44 MHz (unless otherwise noted)

PARAMETER		TEST CONDITIONS	TYP	UNIT
I_{OAGC0}	RF AGC output source current	ATC = 0	300	nA
I_{OAGC1}		ATC = 1	15	μA
$I_{OAGCSINK}$	RF AGC peak sink current	ATC = 0	100	μA
$V_{AGCSP00}$	Start-point IF output level[1]	T1/ATSS = 0, ATP[2:0] = 000	117	dBμV
$V_{AGCSP01}$		T1/ATSS = 0, ATP[2:0] = 001	114	
$V_{AGCSP02}$		T1/ATSS = 0, ATP[2:0] = 010	111	
$V_{AGCSP03}$		T1/ATSS = 0, ATP[2:0] = 011	108	
$V_{AGCSP04}$		T1/ATSS = 0, ATP[2:0] = 100	105	
$V_{AGCSP05}$		T1/ATSS = 0, ATP[2:0] = 101	102	
$V_{AGCSP06}$		T1/ATSS = 0, ATP[2:0] = 110	99	
$V_{AGCSP10}$		T1/ATSS = 1, ATP[2:0] = 000	112	
$V_{AGCSP11}$		T1/ATSS = 1, ATP[2:0] = 001	109	
$V_{AGCSP12}$		T1/ATSS = 1, ATP[2:0] = 010	106	
$V_{AGCSP13}$		T1/ATSS = 1, ATP[2:0] = 011	103	
$V_{AGCSP14}$		T1/ATSS = 1, ATP[2:0] = 100	100	
$V_{AGCSP15}$		T1/ATSS = 1, ATP[2:0] = 101	97	
$V_{AGCSP16}$		T1/ATSS = 1, ATP[2:0] = 110	94	

(1) When AISL = 1, RF AGC function is not available at VHF-L band.

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Electrical Characteristics – Mixer, Oscillator, IF Amplifier

V_{CC} = 5 V, T_A = 25°C, measured in Figure 23 reference measurement circuit at 50-Ω system, IF = 44 MHz,
IF filter characteristics: f_{peak} = 44 MHz (unless otherwise noted)

PARAMETER		TEST CONDITIONS	TYP	UNIT
G_{c1}	Conversion gain (mixer-IF amplifier), VHF-LOW	f_{in} = 57 MHz[1]	35	dB
G_{c3}		f_{in} = 171 MHz[1]	35	
G_{c4}	Conversion gain (mixer-IF amplifier), VHF-HIGH	f_{in} = 177 MHz[1]	35	dB
G_{c6}		f_{in} = 467 MHz[1]	35	
G_{c7}	Conversion gain (mixer-IF amplifier), UHF	f_{in} = 473 MHz[1]	35	dB
G_{c9}		f_{in} = 864 MHz[1]	35	
NF_1	Noise figure, VHF-LOW	f_{in} = 57 MHz	9	dB
NF_3		f_{in} = 171 MHz	9	
NF_4	Noise figure, VHF-HIGH	f_{in} = 177 MHz	9	dB
NF_6		f_{in} = 467 MHz	9	
NF_7	Noise figure, UHF	f_{in} = 473 MHz	12	dB
NF_9		f_{in} = 864 MHz	12	
CM_1	Input voltage causing 1% cross-modulation distortion, VHF-LOW	f_{in} = 57 MHz[2]	79	dBµV
CM_3		f_{in} = 171 MHz[2]	79	
CM_4	Input voltage causing 1% cross-modulation distortion, VHF-HIGH	f_{in} = 177 MHz[2]	79	dBµV
CM_6		f_{in} = 467 MHz[2]	79	
CM_7	Input voltage causing 1% cross-modulation distortion, UHF	f_{in} = 473 MHz[2]	77	dBµV
CM_9		f_{in} = 864 MHz[2]	77	
V_{IFO1}	IF output voltage, VHF-LOW	f_{in} = 57 MHz	117	dBµV
V_{IFO3}		f_{in} = 171 MHz	117	
V_{IFO4}	IF output voltage, VHF-HIGH	f_{in} = 177 MHz	117	dBµV
V_{IFO6}		f_{in} = 467 MHz	117	
V_{IFO7}	IF output voltage, UHF	f_{in} = 473 MHz	117	dBµV
V_{IFO9}		f_{in} = 864 MHz	117	
Φ_{PLVL11}	Phase noise, VHF-LOW	f_{in} = 57 MHz, Offset = 1 kHz[3]	−90	dBc/Hz
Φ_{PLVL12}		f_{in} = 57 MHz, Offset = 10 kHz[4]	−95	
Φ_{PLVL31}		f_{in} = 171 MHz, Offset = 1 kHz[5]	−85	
Φ_{PLVL32}		f_{in} = 171 MHz, Offset = 10 kHz[4]	−95	
Φ_{PLVL41}	Phase noise, VHF-HIGH	f_{in} = 177 MHz, Offset = 1 kHz[3]	−85	dBc/Hz
Φ_{PLVL42}		f_{in} = 177 MHz, Offset = 10 kHz[4]	−90	
Φ_{PLVL61}		f_{in} = 467 MHz, Offset = 1 kHz[5]	−77	
Φ_{PLVL62}		f_{in} = 467 MHz, Offset = 10 kHz[4]	−90	
Φ_{PLVL71}	Phase noise, UHF	f_{in} = 473 MHz, Offset = 1 kHz[3]	−80	dBc/Hz
Φ_{PLVL72}		f_{in} = 473 MHz, Offset = 10 kHz[4]	−85	
Φ_{PLVL91}		f_{in} = 864 MHz, Offset = 1 kHz[5]	−77	
Φ_{PLVL92}		f_{in} = 864 MHz, Offset = 10 kHz[4]	−90	

(1) IF = 44 MHz, RF input level = 70 dBµV, differential output
(2) f_{undes} = f_{des} ±6 MHz, P_{in} = 70 dBµV, AM 1 kHz, 30%, DES/CM = S/I = 46 dB
(3) CP[1:0] = 10 (CP current 350 µA), RS[2:0] = 011 (reference divider 64)
(4) CP[1:0] = 00 (CP current 70 µA), RS[2:0] = 100 (reference divider 128)
(5) CP[1:0] = 11 (CP current 600 µA), RS[2:0] = 011 (reference divider 64)

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Electrical Characteristics – IF Gain Controlled Amplifier

V_{CC} = 5 V, T_A = 25°C, measured in Figure 23 reference measurement circuit at 50-Ω system, IF = 44 MHz, (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
I_{IFGCA}	Input current (IF GCA CTRL)	V_{IFGCA} = 3 V		30	60	μA
$V_{IFGCAMAX}$	Maximum gain control voltage	Gain maximum	2.5		V_{CC}	V
$V_{IFGCAMIN}$	Minimum gain control voltage	Gain minimum	0		0.4	V
$G_{IFGCAMAX}$	Maximum gain	V_{IFGCA} = 3 V	49	53	57	dB
$G_{IFGCAMIN}$	Minimum gain	V_{IFGCA} = 0 V	−4	−1	2	dB
GCR_{IFGCA}	Gain control range	V_{IFGCA} = 0–3 V		54		dB
$V_{IFGCAOUT}$	Output voltage	Single-ended output		2.1		Vp-p
NF_{IFGCA}	Noise figure	V_{IFGCA} = 3 V		8.5		dB
$IM3_{IFGCA}$	Third order intermodulation distortion	$f_{IFGCAIN1}$ = 43 MHz, $f_{IFGCAIIN2}$ = 44 MHz, $V_{IFGCAOUT}$ = −2 dBm, V_{IFGCA} = 3 V		−50		dBc
$IIP3_{IFGCA}$	Input intercept point	V_{IFGCA} = 0 V		11		dBm
$R_{IFGCAIN}$	Input resistance (IF GCA IN1, IF GCA IN2)			1		kΩ

FUNCTIONAL DESCRIPTION

I²C Bus Mode

I²C Write Mode (R/$\overline{W}$ = 0)

Table 1. Write Data Format

	MSB							LSB	(1)
Address byte (ADB)	1	1	0	0	0	MA1	MA0	R/$\overline{W}$ = 0	A
Divider byte 1 (DB1)	0	N14	N13	N12	N11	N10	N9	N8	A
Divider byte 2 (DB2)	N7	N6	N5	N4	N3	N2	N1	N0	A
Control byte 1 (CB1)	1	0	ATP2	ATP1	ATP0	RS2	RS1	RS0	A
Band-switch byte (BB)	CP1	CP0	AISL	P5	BS4	BS3	BS2	BS1	A
Control byte 2 (CB2)	1	1	ATC	STBY	T3	T2	T1/ATSS	T0/XLO	A

(1)   A: Acknowledge

Table 2. Write Data Symbol Description

SYMBOL	DESCRIPTION	DEFAULT
MA[1:0]	Address-set bits (see Table 3)	
N[14:0]	Programmable counter set bits $N = N14 \times 2^{14} + N13 \times 2^{13} + ... + N1 \times 2 + N0$	N14 = N13 = N12 = ... = N0 = 0
ATP[2:0]	RF AGC start-point control bits (see Table 4)	ATP[2:0] = 011
RS[2:0]	Reference divider ratio-selection bits (see Table 5)	RS[2:0] = 111
CP[1:0]	Charge-pump current-set bit (see Table 6)	CP[1:0] = 11
AISL	RF AGC detector input selection bit AISL = 0: IF amplifier AISL = 1: Mixer output	AISL = 0
P5	Port output/ADC input control bit P5 = 0: ADC INPUT P5 = 1: Tr = ON	P5 = 0
BS[4:1]	Band-switch control bits BSn = 0: Tr = OFF BSn = 1: Tr = ON Band selection by BS[1:2] **BS1 BS2** 1 0 VHF-LO 0 1 VHF-HI 0 0 UHF 1 1 Reserved	BSn = 0
ATC	RF AGC current-set bit ATC = 0: Current = 300 nA ATC = 1: Current = 15 μA	ATC = 0
STBY	Power standby mode-control bit STBY = 0: Normal operation STBY = 1: Standby mode/stop MOP function (XTALOUT is available even in standby mode)	STBY = 0
T3, T2, T1/ATSS, T0/XLO	TEST bits, RFAGC shift bit, XTAL OUT control bit (see Table 7)	T[3:0] = 0010
X	Don't care	

Table 3. Address Selection

MA1	MA0	VOLTAGE APPLIED ON AS INPUT
0	0	0 V to 0.1 V_{CC} (Low)
0	1	OPEN, or 0.2 V_{CC} to 0.3 V_{CC} (Mid2)
1	0	0.4 V_{CC} to 0.6 V_{CC} (Mid1)
1	1	0.9 V_{CC} to V_{CC} (High)

Table 4. RF AGC Start Point[1]

T1/ATSS	ATP2	ATP1	ATP0	IF OUT LEVEL (dBμV)
0	0	0	0	117
0	0	0	1	114
0	0	1	0	111
0	0	1	1	108
0	1	0	0	105
0	1	0	1	102
0	1	1	0	99
0	1	1	1	Disabled
1	0	0	0	112
1	0	0	1	109
1	0	1	0	106
1	0	1	1	103
1	1	0	0	100
1	1	0	1	97
1	1	1	0	94
1	1	1	1	Disabled

(1)   When AISL = 1, RF AGC function is not available at VHF-L band (output level is undefined).

Table 5. Reference Divider Ratio

RS2	RS1	RS0	REFERENCE DIVIDER RATIO
0	0	0	24
0	0	1	28
0	1	0	50
0	1	1	64
1	0	0	128
1	X	1	80

Table 6. Charge-Pump Current

CP1	CP0	CHARGE PUMP CURRENT (μA)
0	0	70
0	1	140
1	0	350
1	1	600

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Table 7. Test Bits/XTAL OUT Control [1]

T3	T2	T1/ATSS	T0/XLO	DEVICE OPERATION	XTAL OUT 4-MHz OUTPUT
0	0	X	0	Normal operation	Enabled
0	0	X	1	Normal operation	Disabled
X	1	X	X	Test mode	Not available
1	X	X	X	Test mode	Not available

(1)   RF AGC and XTAL OUT are not available in test mode.

Example I²C Data Write Sequences

Telegram examples:

Start-ADB-DB1-DB2-CB1-BB-CB2-Stop
Start-ADB-DB1-DB2-Stop
Start-ADB-CB1-BB-CB2-Stop
Start-ADB-CB1-BB-Stop
Start-ADB-CB2-Stop

Abbreviations:

ADB: Address byte
BB: Band-switch byte
CB1: Control byte 1
CB2: Control byte 2
DB1: Divider byte 1
DB2: Divider byte 2
Start: Start condition
Stop: Stop condition

I²C Read Mode (R/$\overline{\text{W}}$ = 1)

Table 8. Read Data Format (A: Acknowledge)

	MSB							LSB	
Address byte (ADB)	1	1	0	0	0	MA1	MA0	R/$\overline{\text{W}}$ = 1	A
Status byte (SB)	POR	FL	1	1	X	A2	A1	A0	–

Table 9. Read Data Symbol Description

SYMBOL	DESCRIPTION	DEFAULT
MA[1:0]	Address set bits (see Table 3)	
POR	Power-on-reset flag POR set: power on POR reset: end-of-data transmission procedure	POR = 1
FL	In-lock flag PLL locked (FL = 1), unlocked (FL = 0)	
A[2:0]	Digital data of ADC (see Table 10) Bit P5 must be set to 0.	

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Table 10. ADC Level[1]

A2	A1	A0	VOLTAGE APPLIED ON ADC INPUT
1	0	0	0.6 V_{CC} to V_{CC}
0	1	1	0.45 V_{CC} to 0.6 V_{CC}
0	1	0	0.3 V_{CC} to 0.45 V_{CC}
0	0	1	0.15 V_{CC} to 0.3 V_{CC}
0	0	0	0 V to 0.15 V_{CC}

(1) Accuracy is $0.03 \times V_{CC}$.
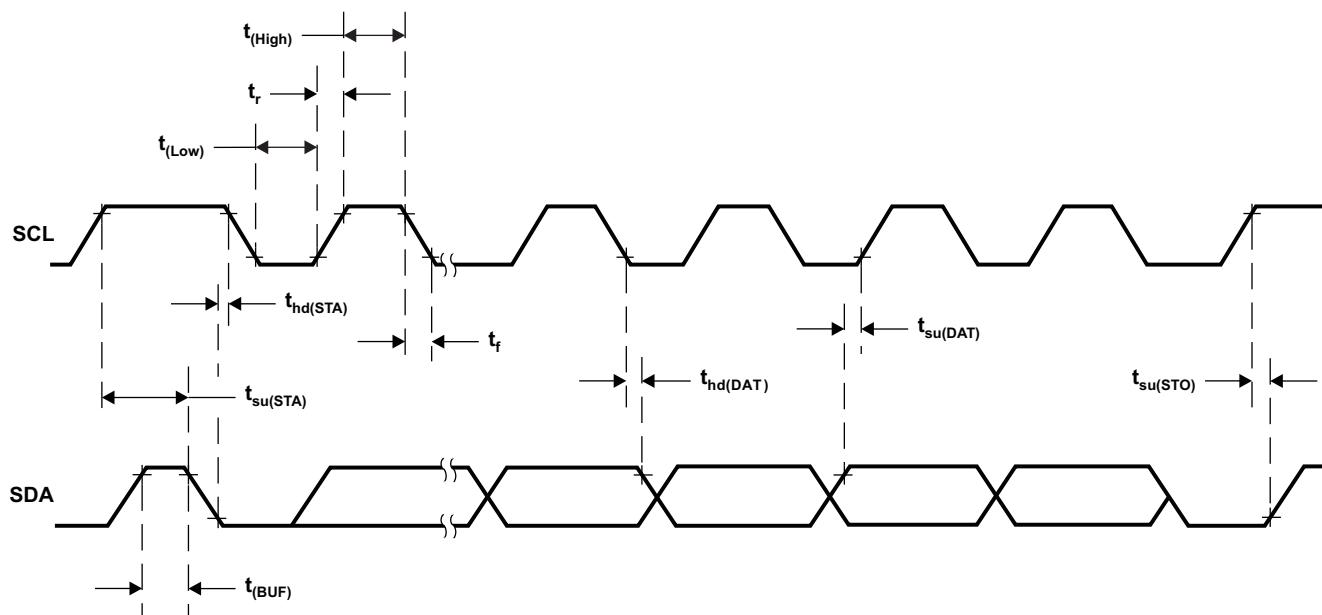
Figure 22. I^{2}C Timing Chart

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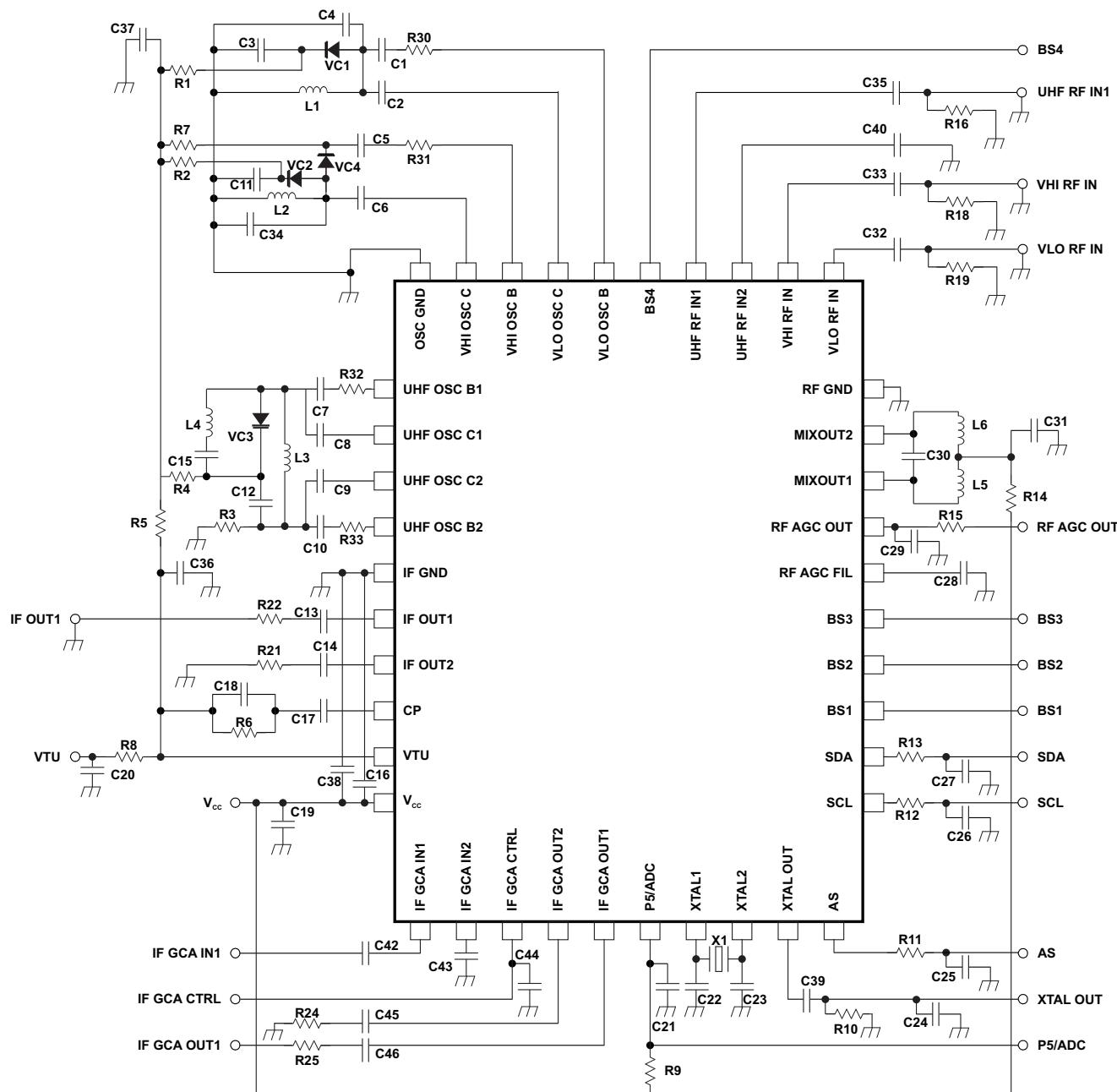
NOTE: This application information is advisory, and a performance check is required for actual application circuits. TI assumes no responsibility for the consequences of the use of this circuit, nor for any infringement of patent or patent rights of third parties that may result from its use.

Figure 23. Reference Measurement Circuit

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APPLICATION INFORMATION (continued)

Component Values for Measurement Circuit

PART NAME	VALUE	PART NAME	VALUE
C1 (VLO OSC B)	1 pF	C43 (IF GCA IN2)	2.2 nF
C2 (VLO OSC C)	2 pF	C44 (IF GCA CTRL)	2.2 nF
C3 (VLO OSC)	47 pF	C45 (IF GCA OUT1)	2.2 nF
C4 (VLO OSC)	Open	C46 (IF GCA OUT2)	2.2 nF
C5 (VHI OSC)	7 pF	L1 (VLO OSC)	φ3.0 mm, 7T, wire 0.32 mm
C6 (VHI OSC C)	5 pF	L2 (VHI OSC)	φ2.0 mm, 3T, wire 0.4 mm
C7 (UHF OSC B1)	1.5 pF	L3 (UHF OSC)	φ1.8 mm, 3T, wire 0.4 mm
C8 (UHF OSC C1)	1 pF	L4 (UHF OSC)	φ1.8 mm, 3T, wire 0.4 mm
C9 (UHF OSC C2)	1 pF	L5 (MIX OUT)	680 nH (LK1608R68K-T)
C10 (UHF OSC B2)	1.5 pF	L6 (MIX OUT)	680 nH (LK1608R68K-T)
C11 (VHI OSC)	51 pF	R1 (VLO OSC)	3.3 kΩ
C12 (UHF OSC)	10 pF	R2 (VHI OSC)	3.3 kΩ
C13 (IF OUT)	2.2 nF	R3 (UHF OSC)	2.2 kΩ
C14 (IF OUT)	2.2 nF	R4 (UHF OSC)	1 kΩ
C15 (UHF OSC)	100 pF	R5 (VTU)	3 kΩ
C16 (V_{CC})	4.7 nF	R6 (CP)	47 kΩ
C17 (CP)	0.01 µF/50 V	R7 (VHI OSC)	3.3 kΩ
C18 (CP)	22 pF/50 V	R8 (VTU)	22 kΩ
C19 (V_{CC})	2.2 nF	R9 (P5/ADC)	Open
C20 (VTU)	2.2 nF/50 V	R10 (XTALOUT)	5.1 kΩ
C21 (P5/ADC)	Open	R11 (AS)	330 Ω
C22 (XTAL)	27 pF	R12 (SCL)	330 Ω
C23 (XTAL)	27 pF	R13 (SDA)	330 Ω
C24 (XTALOUT)	10 pF	R14 (V_{CC})	0
C25 (AS)	Open	R15 (RF AGC OUT)	0
C26 (SCL)	Open	R16 (UHF RF IN1)	(50 Ω)
C27 (SDA)	Open	R18 (VHI RF IN)	(50 Ω)
C28 (AGC FIL)	Open	R19 (VLO RF IN)	(50 Ω)
C29 (RF AGC OUT)	0.15 µF	R21 (IF OUT2)	1 kΩ
C30 (MIX OUT)	5.6 pF	R22 (IF OUT1)	1 kΩ
C31 (MIX OUT)	2.2 nF	R24 (IF GCA OUT1)	250 Ω
C32 (VLO RF IN)	2.2 nF	R25 (IF GCA OUT2)	200 Ω
C33 (VHI RF IN)	2.2 nF	R30 (VLO OSC B)	0
C34 (VHI OSC)	0.5 pF	R31 (VHI OSC B)	4.7 Ω
C35 (UHF RF IN1)	2.2 nF	R32 (UHF OSC B1)	0
C36 (VTU)	22 pF	R33 (UHF OSC B2)	0
C37 (VTU)	2.2 nF/50 V	VC1 (VLO OSC)	MA2S374
C38 (V_{CC})	0.1 µF	VC2 (VHI OSC)	MA2S374
C39 (XTAL OUT)	2.2 nF	VC3 (UHF OSC)	MA2S372
C40 (UHF RF IN2)	2.2 nF	VC4 (VHI OSC)	MA2S372
C42 (IF GCA IN1)	2.2 nF	X1	4-MHz crystal

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APPLICATION INFORMATION (CONTINUED)

Test Circuits
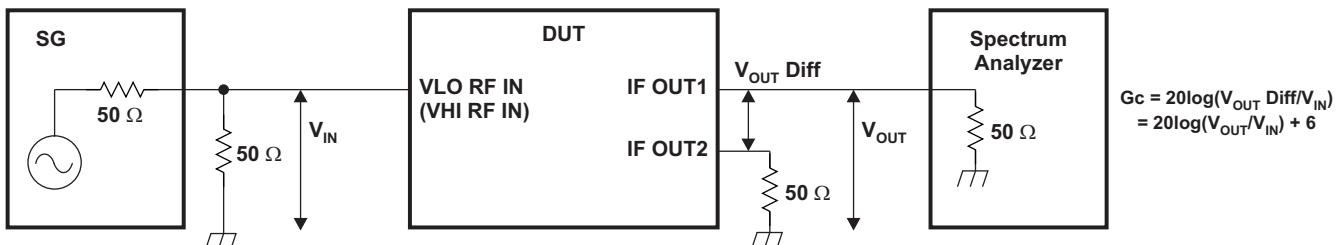
Figure 24. VHF-Conversion Gain-Measurement Circuit

$Gc = 20\log(V_{OUT} \text{ Diff}/V_{IN})$
$= 20\log(V_{OUT}/V_{IN}) + 6$
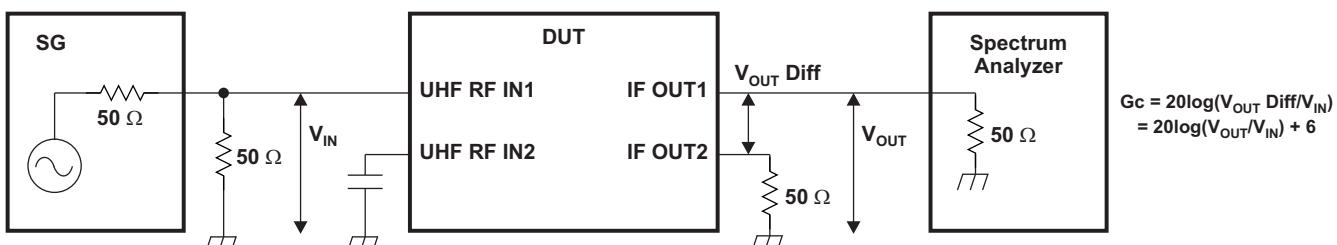
Figure 25. UHF-Conversion Gain-Measurement Circuit

$Gc = 20\log(V_{OUT} \text{ Diff}/V_{IN})$
$= 20\log(V_{OUT}/V_{IN}) + 6$
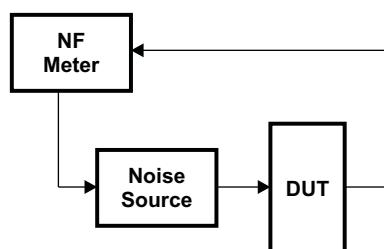
Figure 26. Noise-Figure Measurement Circuit
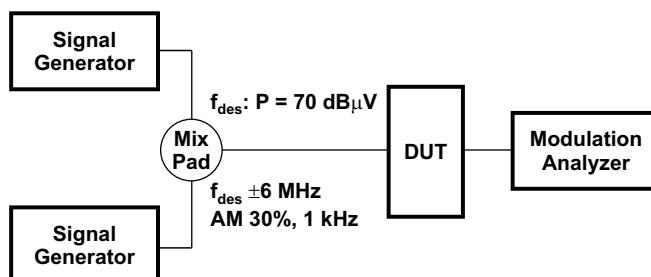
Figure 27. 1% Cross-Modulation Distortion Measurement Circuit

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TYPICAL CHARACTERISTICS

Band-Switch Driver Output Voltage (BS1−BS4)

BS OUTPUT CURRENT
vs
OUTPUT VOLTAGE
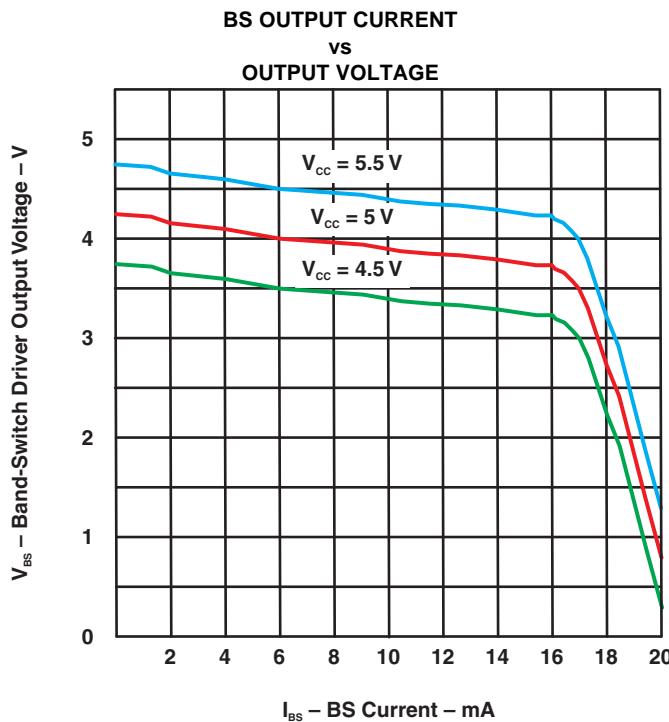
Figure 28. Band-Switch Driver Output Voltage

S-Parameter
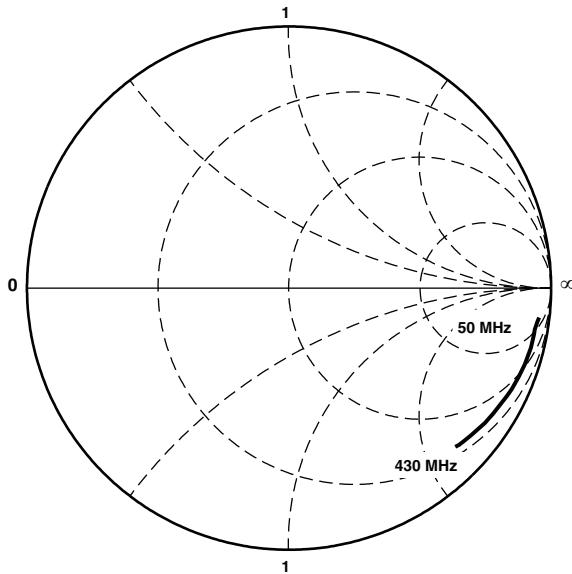
Figure 29. VLO RFIN, VHI RFIN

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TYPICAL CHARACTERISTICS (continued)
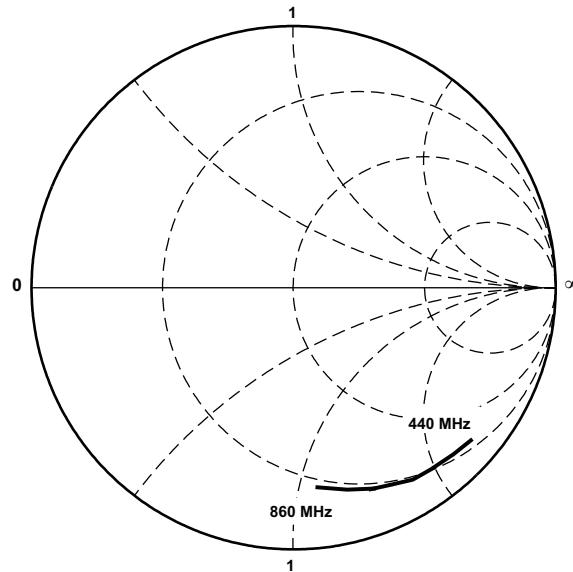
Figure 30. UHF RFIN
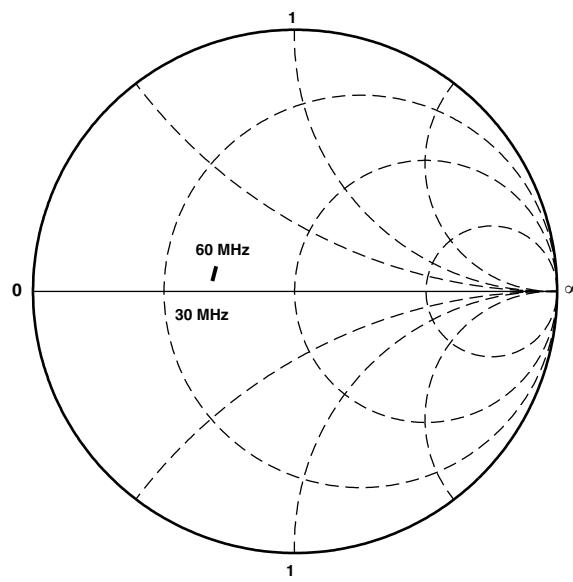
Figure 31. IF OUT

TYPICAL CHARACTERISTICS (continued)

IF GCA GAIN
vs
CONTROL VOLTAGE
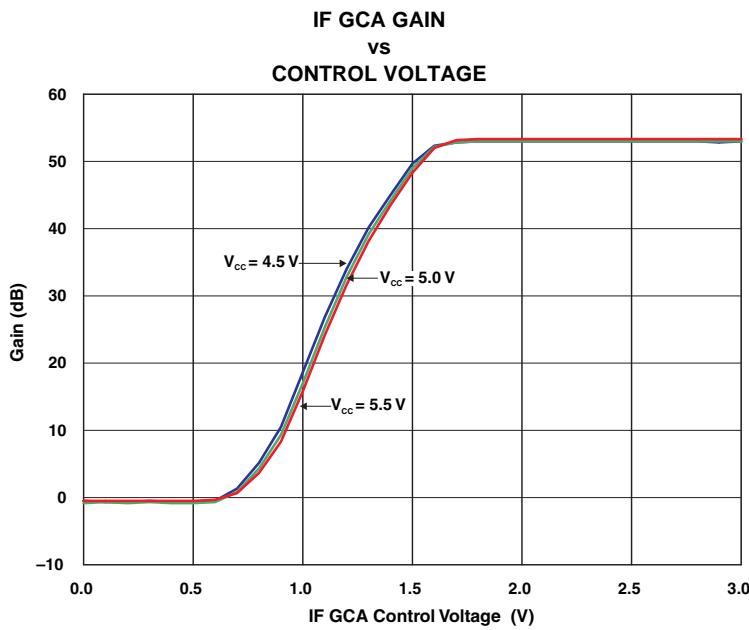
Figure 32.

PACKAGING INFORMATION

Orderable Device	Status [1]	Package Type	Package Drawing	Pins	Package Qty	Eco Plan [2]	Lead/Ball Finish	MSL Peak Temp [3]
SN761667RHAR	PREVIEW	QFN	RHA	40		TBD	Call TI	Call TI

[1] The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

[2] Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check
http://www.ti.com/productcontent for the latest availability information and additional product content details.
TBD: The Pb-Free/Green conversion plan has not been defined.
Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.
Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.
Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

[3] MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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RHA (S−PQFP−N40)   **PLASTIC QUAD FLATPACK**

Pin 1 Index Area
Top and Bottom

0,20 Nominal
Lead Frame

Seating Plane

Exposed Thermal Pad
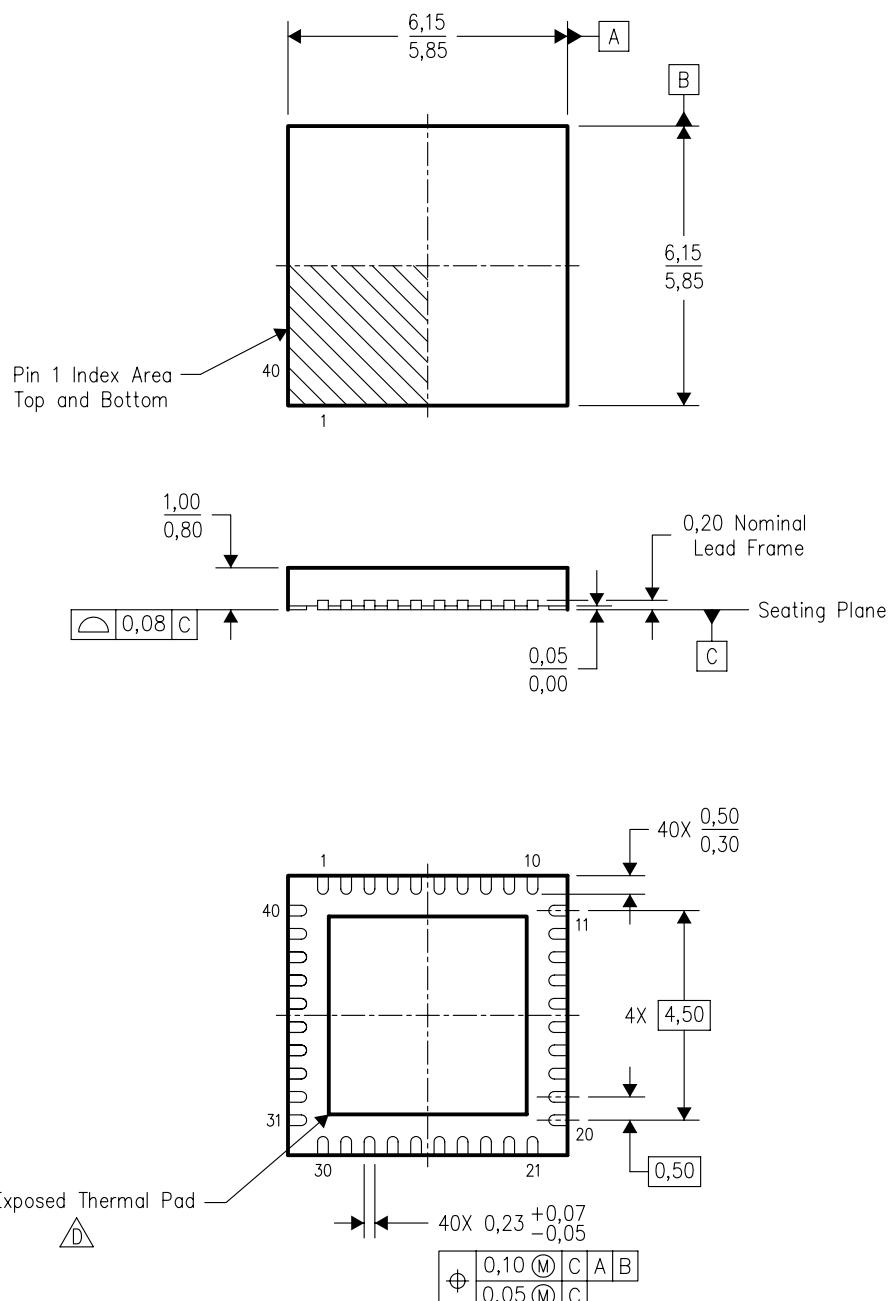
Bottom View

4204276/C 12/2004

NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M−1994.
      B. This drawing is subject to change without notice.
      C. QFN (Quad Flatpack No−Lead) Package configuration.
      D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
         See the Product Data Sheet for details regarding the exposed thermal pad dimensions.
      E. Package complies to JEDEC MO−220 variation VJJD−2.

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